

MMT05A230T3, MMT05A260T3, MMT05A310T3

Preferred Devices

Thyristor Surge Protectors

High Voltage Bidirectional TSPD

These Thyristor Surge Protective devices (TSPD) prevent overvoltage damage to sensitive circuits by lightning, induction and power line crossings. They are breakover-triggered crowbar protectors. Turn-off occurs when the surge current falls below the holding current value.

Secondary protection applications for electronic telecom equipment at customer premises.

- High Surge Current Capability: **50 Amps** 10 x 1000 μ sec; for Controlled Temperature Environments in the **SMA** package
- The MMT05A230T3 Series is used to help equipment meet various regulatory requirements including: Telcordia 1089, ITU K.20 & K.21, IEC 950 and FCC Part 68
- Bidirectional Protection in a Single Device
- Little Change of Voltage Limit with Transient Amplitude or Rate
- Freedom from Wearout Mechanisms Present in Non-Semiconductor Devices
- Fail-Safe, Shorts When Overstressed, Preventing Continued Unprotected Operation
- Surface Mount Technology (SMT)
-  Indicates UL Registered – File #E210057
- Device Marking: MMT05A230T3: PBF; MMT05A260T3: PBG; MMT05A310T3: PBJ

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Off-State Voltage – Maximum MMT05A230T3 MMT05A260T3 MMT05A310T3	V_{DM}	± 170 ± 200 ± 270	Volts
Maximum Pulse Surge Short Circuit Current Non-Repetitive Double Exponential Decay Waveform (Notes 1 and 2) 8 x 20 μ sec 10 x 160 μ sec 10 x 560 μ sec 10 x 1000 μ sec	I_{PPS1} I_{PPS2} I_{PPS3} I_{PPS4}	± 150 ± 100 ± 70 ± 50	A(pk)
Maximum Non-Repetitive Rate of Change of On-State Current Double Exponential Waveform, $I_{PK} = 50$ A, $P_W = 15$ μ s	di/dt	± 100	A/ μ s

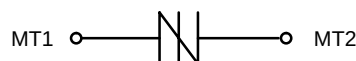
1. Allow cooling before testing second polarity.
2. Measured under pulse conditions to reduce heating.



ON Semiconductor®

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BIDIRECTIONAL TSPD 50 AMP SURGE 265 thru 365 VOLTS



SMA
(No Polarity)
CASE 403D

MARKING DIAGRAM



xxx = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week

ORDERING INFORMATION

Device	Package	Shipping†
MMT05A230T3	SMA	12 mm Tape and Reel (5 K/Reel)
MMT05A260T3	SMA	12 mm Tape and Reel (5 K/Reel)
MMT05A310T3	SMA	12 mm Tape and Reel (5 K/Reel)

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

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THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Operating Temperature Range Blocking or Conducting State	T_{J1}	-40 to +125	°C
Overload Junction Temperature – Maximum Conducting State Only	T_{J2}	+175	°C
Instantaneous Peak Power Dissipation ($I_{pk} = 50A$, 10x1000 μsec @ 25°C)	P_{PK}	2000	W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	T_L	260	°C

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ C$ unless otherwise noted)

Devices are bidirectional. All electrical parameters apply to forward and reverse polarities.

Characteristics	Symbol	Min	Typ	Max	Unit
Breakover Voltage (Both polarities) ($dv/dt = 100 V/\mu s$, $I_{SC} = 1.0 A$, $V_{dc} = 1000 V$) (+65°C) MMT05A230T3 MMT05A260T3 MMT05A310T3 MMT05A230T3 MMT05A260T3 MMT05A310T3	$V_{(BO)}$	- - - - - -	- - - - - -	265 320 365 280 340 400	Volts
Breakover Voltage (Both polarities) ($f = 60 Hz$, $I_{SC} = 1.0 A(rms)$, $V_{OC} = 1000 V(rms)$, $R_I = 1.0 k\Omega$, $t = 0.5 cycle$) (Note 3) (+65°C) MMT05A230T3 MMT05A260T3 MMT05A310T3 MMT05A230T3 MMT05A260T3 MMT05A310T3	$V_{(BO)}$	- - - - - -	- - - - - -	265 320 365 280 340 400	Volts
Breakover Voltage Temperature Coefficient	$dV_{(BO)}/dT_J$	-	0.08	-	%/°C
Breakdown Voltage ($I_{(BR)} = 1.0 mA$) Both polarities MMT05A230T3 MMT05A260T3 MMT05A310T3	$V_{(BR)}$	- - -	190 240 280	- - -	Volts
Off State Current ($V_{D1} = 50 V$) Both polarities ($V_{D2} = V_{DM}$) Both polarities	I_{D1} I_{D2}	- -	- -	2.0 5.0	μA
On-State Voltage ($I_T = 1.0 A$) ($PW \leq 300 \mu s$, Duty Cycle $\leq 2\%$) (Note 3)	V_T	-	1.53	3.0	Volts
Breakover Current ($f = 60 Hz$, $V_{DM} = 1000 V(rms)$, $R_S = 1.0 k\Omega$) Both polarities	I_{BO}	-	230	-	mA
Holding Current (Both polarities) (Note 3) $V_S = 500 Volts$; I_T (Initiating Current) = $\pm 1.0 Amp$	I_H	150	340	-	mA
Critical Rate of Rise of Off-State Voltage (Linear waveform, $V_D = Rated V_{BR}$, $T_J = 25^\circ C$)	dv/dt	2000	-	-	$V/\mu s$
Capacitance ($f = 1.0 MHz$, 50 Vdc, 1.0 V(rms) Signal) ($f = 1.0 MHz$, 2.0 Vdc, 1.0 V(rms) Signal)	C_O	- -	22 35	- 50	pF

3. Measured under pulse conditions to reduce heating.

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Voltage Current Characteristic of TSPD (Bidirectional Device)

Symbol	Parameter
I_{D1}, I_{D2}	Off State Leakage Current
V_{D1}, V_{D2}	Off State Blocking Voltage
V_{BR}	Breakdown Voltage
V_{BO}	Breakover Voltage
I_{BO}	Breakover Current
I_H	Holding Current
V_{TM}	On State Voltage

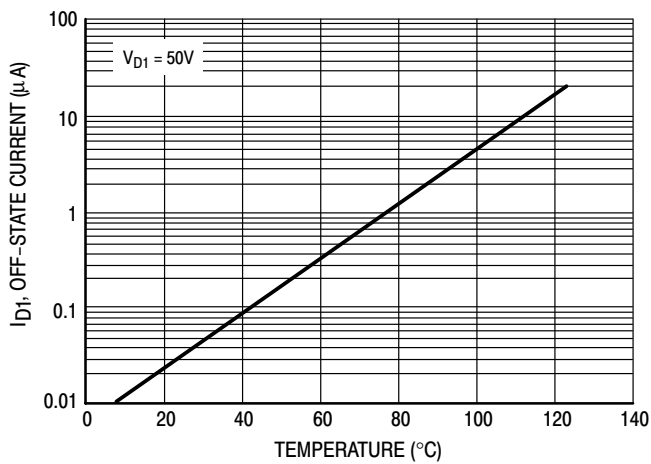
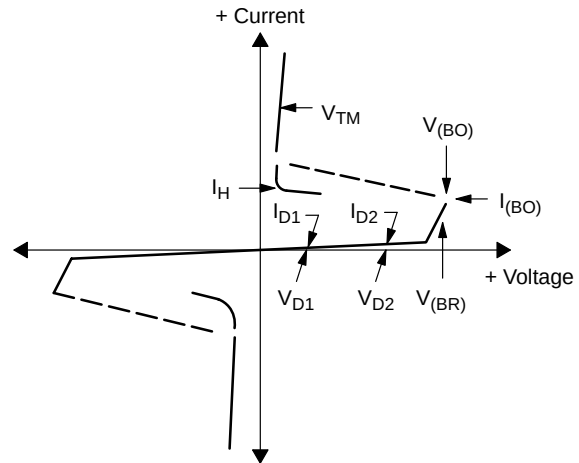


Figure 1. Off-State Current versus Temperature

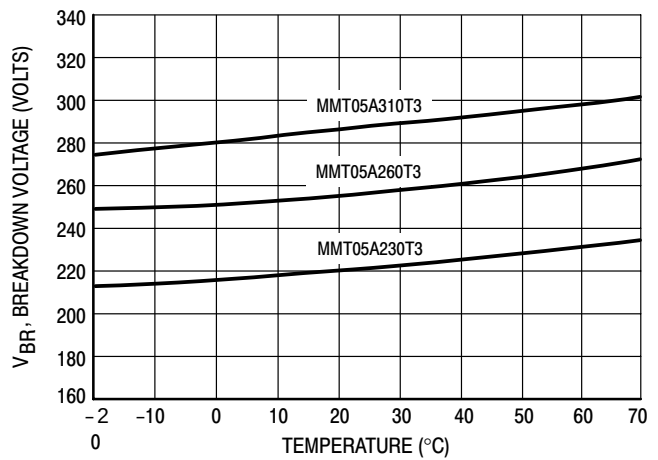


Figure 2. Typical Breakdown Voltage versus Temperature

MMT05A230T3, MMT05A260T3, MMT05A310T3

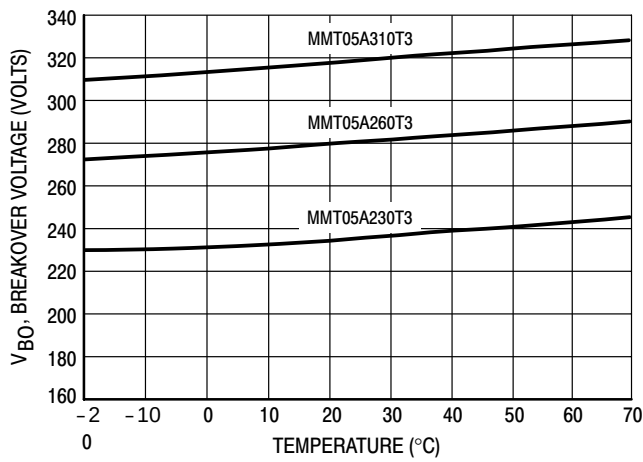


Figure 3. Typical Breakover Voltage versus Temperature

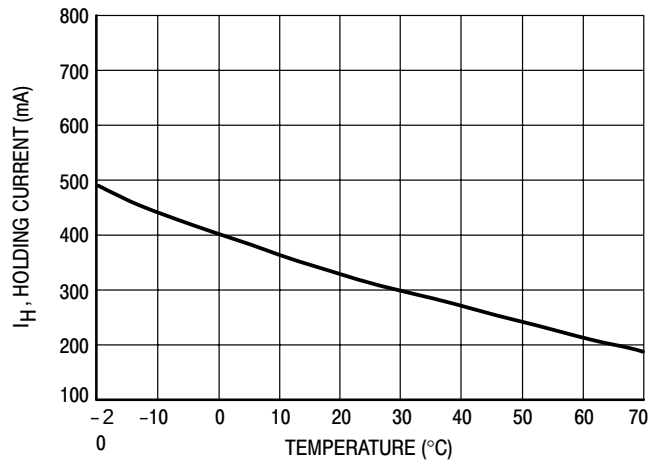


Figure 4. Typical Holding Current versus Temperature

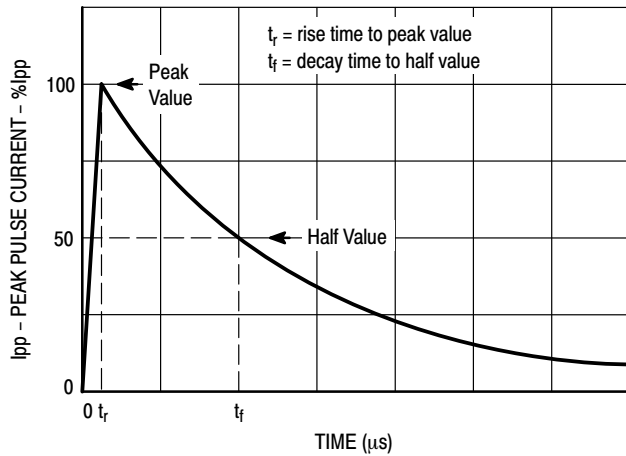


Figure 5. Exponential Decay Pulse Waveform

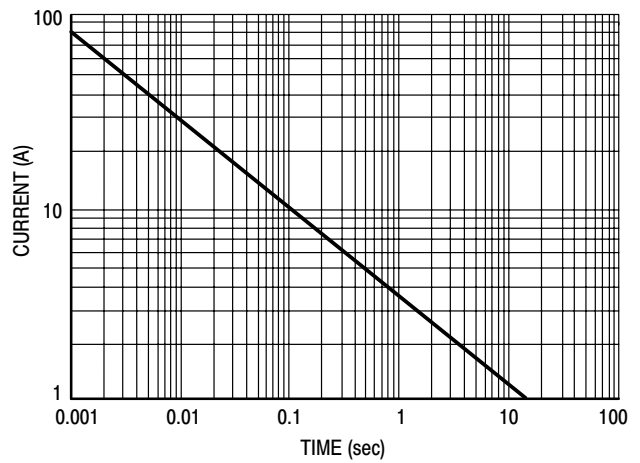
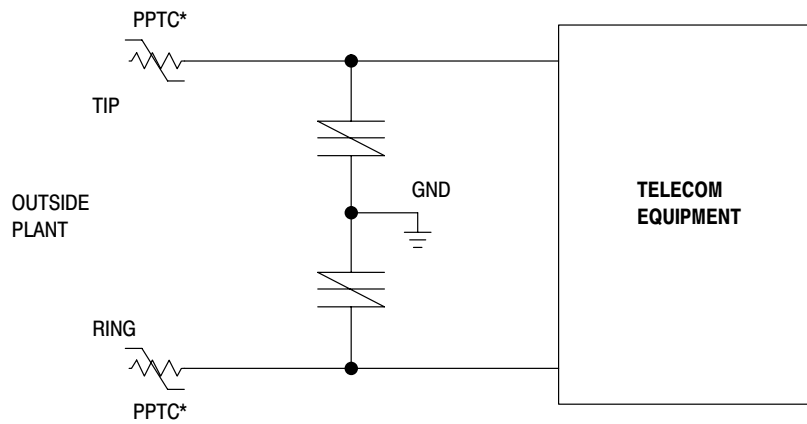
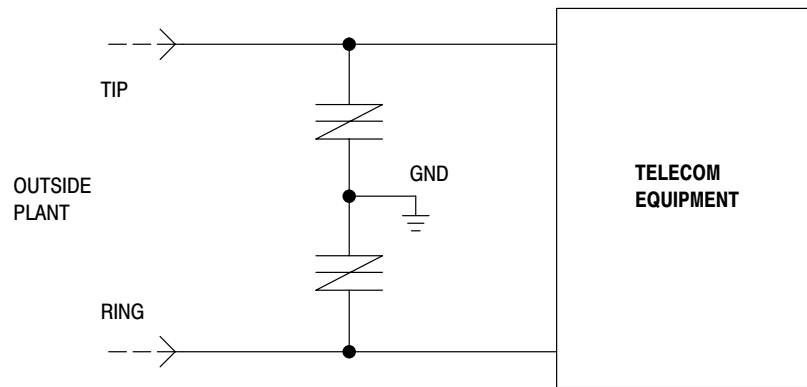
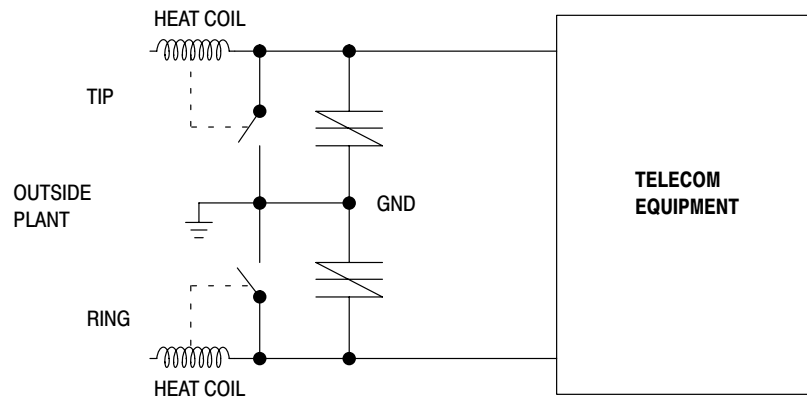


Figure 6. Peak Surge On-State Current versus Surge Current Duration, Sinusoidal Waveform

MMT05A230T3, MMT05A260T3, MMT05A310T3



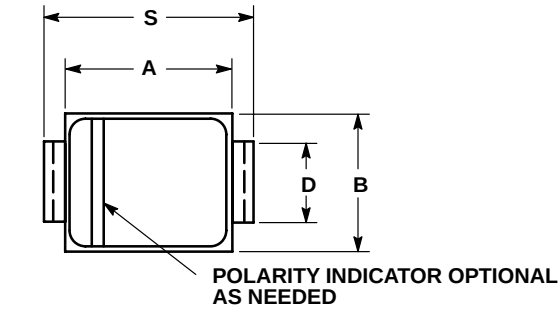
*Polymeric PTC (positive temperature coefficient) overcurrent protection device



MMT05A230T3, MMT05A260T3, MMT05A310T3

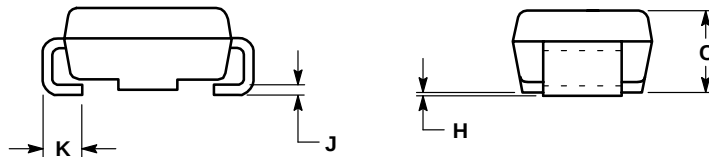
PACKAGE DIMENSIONS

SMA
CASE 403D-02
ISSUE A

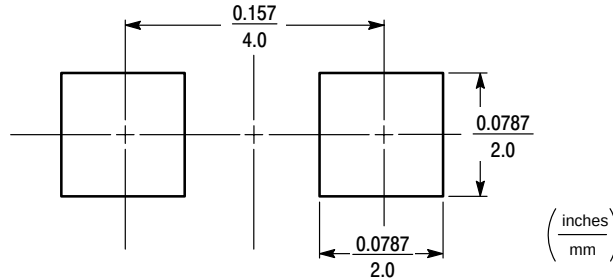


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 403D-01 OBSOLETE, NEW STANDARD IS 403D-02.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.160	0.180	4.06	4.57
B	0.090	0.115	2.29	2.92
C	0.075	0.095	1.91	2.41
D	0.050	0.064	1.27	1.63
H	0.002	0.006	0.05	0.15
J	0.006	0.016	0.15	0.41
K	0.030	0.060	0.76	1.52
S	0.190	0.220	4.83	5.59



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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